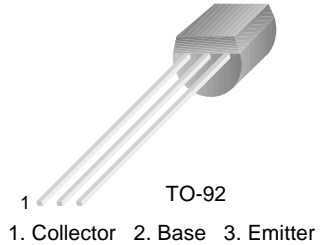


## TIS93

### PNP General Purpose Amplifier

- This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500mA.



### Absolute Maximum Ratings\* $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	-40	V
$V_{CBO}$	Collector-Base Voltage	-40	V
$V_{EBO}$	Emitter-Base Voltage	-5.0	V
$I_C$	Collector Current - Continuous	-800	mA
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	- 55 ~ 150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

### Electrical Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
<b>Off Characteristics</b>					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage *	$I_C = -10\text{mA}, I_B = 0$	-40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -100\mu\text{A}, I_E = 0$	-40		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -100\mu\text{A}, I_C = 0$	-5.0		V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = -20\text{V}, I_E = 0$		-100	nA
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = -3.0\text{V}, I_C = 0$		- 100	nA
<b>On Characteristics</b>					
$h_{FE}$	DC Current Gain	$V_{CE} = -2.0\text{V}, I_C = -50\text{mA}$	100	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -50\text{mA}, I_B = -5.0\text{mA}$		-0.25	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -2.0\text{V}, I_C = -50\text{mA}$		-1.0	V

\* Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

**Thermal Characteristics**  $T_A=25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Max.	Units
$P_D$	Total Device Dissipation	625	mW
	Derate above $25^\circ\text{C}$	5.0	$\text{mW}/^\circ\text{C}$
$R_{\theta\text{JC}}$	Thermal Resistance, Junction to Case	83.3	$^\circ\text{C}/\text{W}$
$R_{\theta\text{JA}}$	Thermal Resistance, Junction to Ambient	200	$^\circ\text{C}/\text{W}$

# Package Dimensions

TIS93

## TO-92



Dimensions in Millimeters

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## PRODUCT STATUS DEFINITIONS

### Definition of Terms

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